



# Investigation of NbN thin films on small, flat samples

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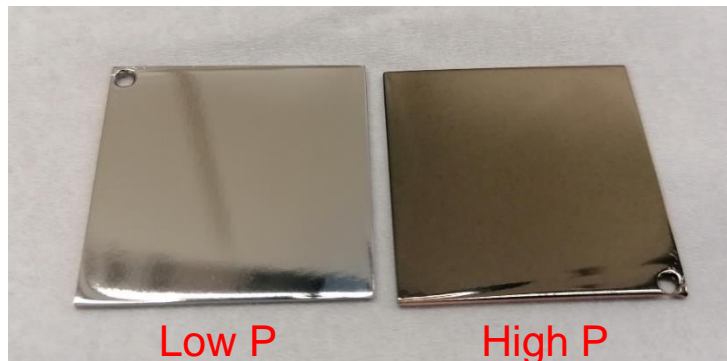
# NbN Optimisation Samples

- NbN thin films optimised based on screening study
- Requirements:
  - Dense film
  - Gold film
  - Columnar, cubic structure
  - Higher  $T_c$  and  $B_{en}$
  - Smoother Surface
- Optimisation Study:
  - Nitrogen percentage variation
  - Bias effects
  - Pressure variation
  - Optimisation
  - Multilayer samples

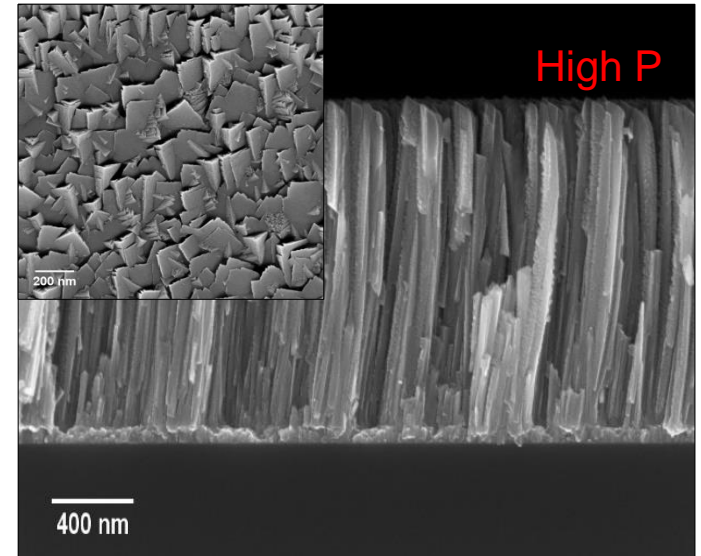
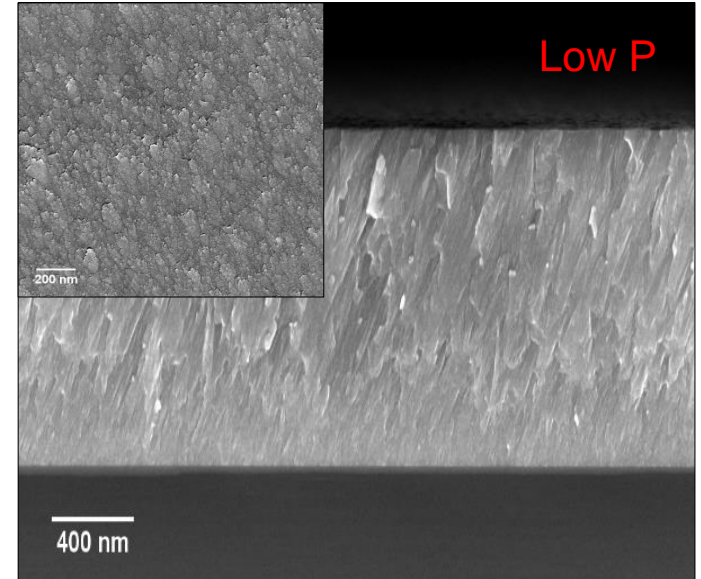


- Lower Pressure leads to denser films (no specific structure) and rounded grains
- Higher deposition pressure (> 1200 mPa) leads to columnar grain structure with faceted surface features
  - Larger crystallite sizes and rougher surface
- Film colour changes from silver (Hex) to gold (Cubic)
- Increased Oxygen at higher pressure

Pressure	Sq (nm)	Crystallite Size (nm)
600 mPa	4.39 ± 0.41	74
1000 mPa	12.14 ± 1.54	295
1400 mPa	16.70 ± 1.72	306
1800 mPa	21.86 ± 2.22	385



**Silver:** Hexagonal NbN sample. **Gold:** Cubic NbN sample

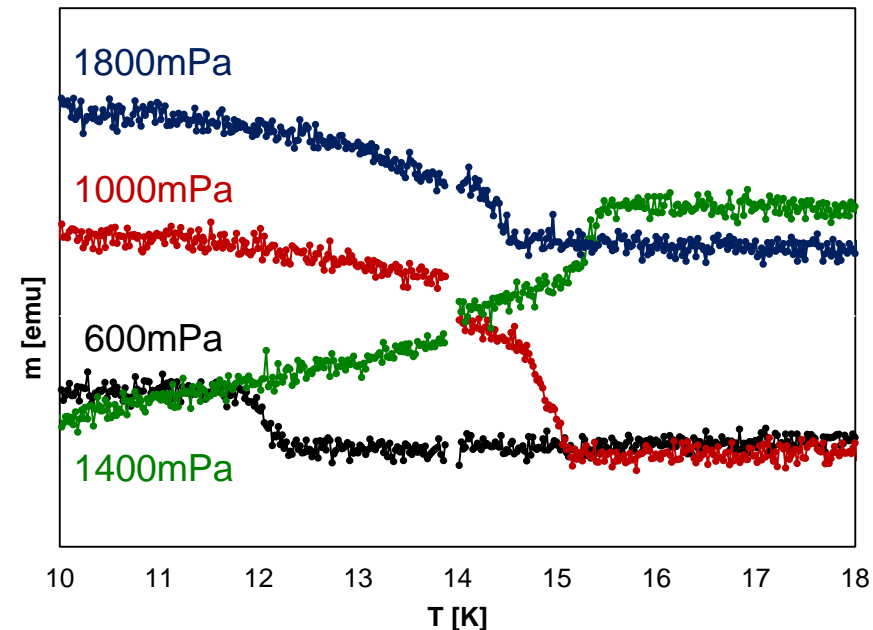
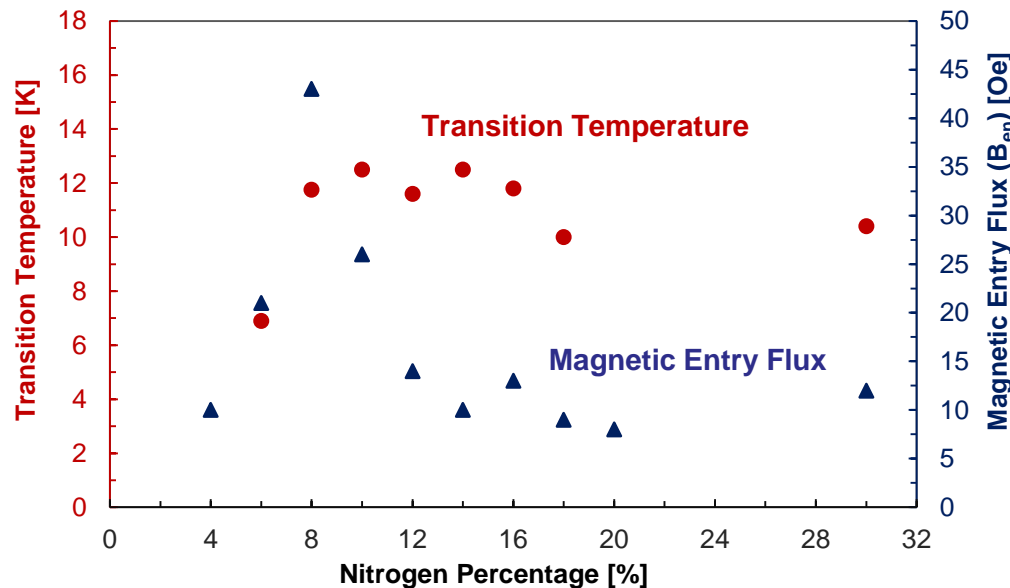


**Top:** Low pressure film. **Bottom:** High pressure film

# NbN Superconducting Results

- VSM used for measurements
- Nitrogen variation:
  - $T_c$  stable from 8%  $N_2 = \pm 12K$
  - $B_{en}$  max found at 8%  $N_2$
- Pressure variation:
  - Increase in  $T_c$  with increasing pressure.
  - Decrease in  $T_c$  for 1800mPa = Oxynitrides?

Pressure	Transition Temp [K]	Flux of first entry (2%) @4.2K [Oe]
600 mPa	12.1	35
1000 mPa	14.9	40
1400 mPa	15.3	23
1800 mPa	14.5	20



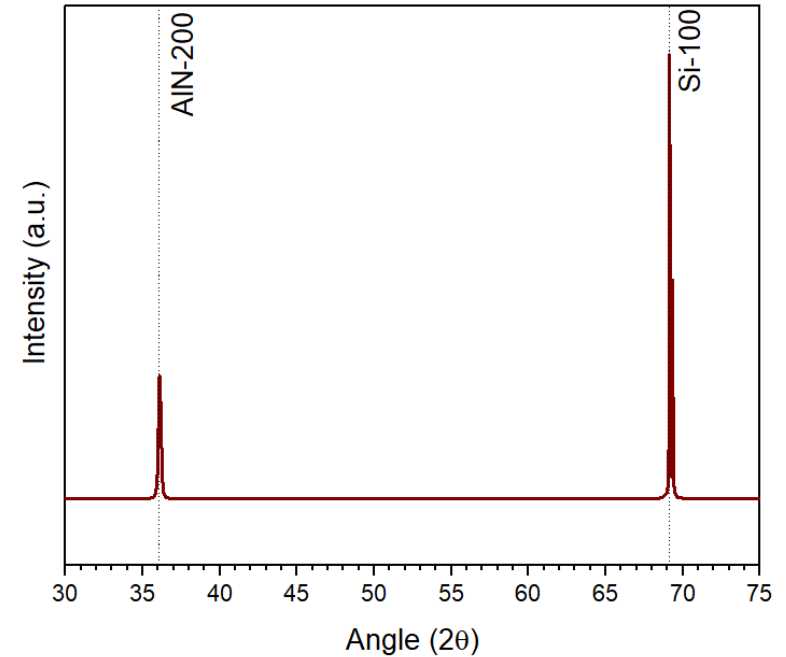
# AlN Deposition Trials

- AlN thin film trials with DCMS completed
  - Target melted due to high power

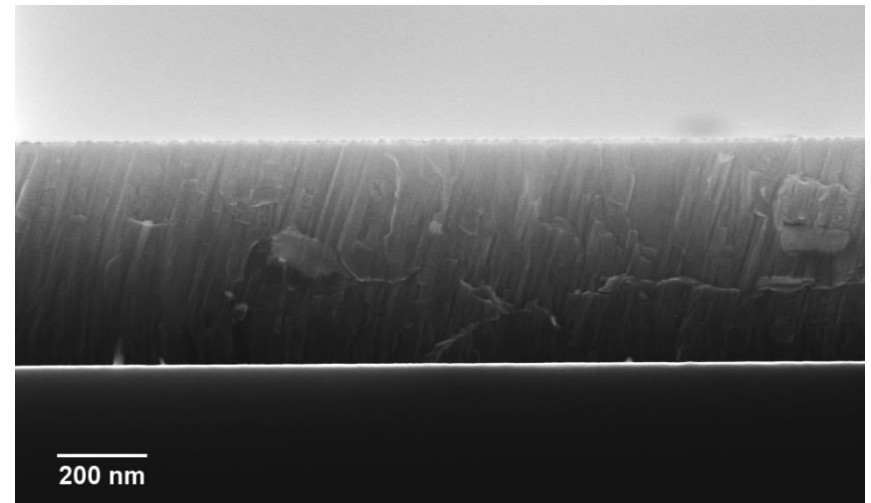


# AlN Deposition Trials

- AlN thin film trials with DCMS completed
  - Target melted due to high power
  - AlN(200) matches  $\delta$ -NbN(111)
  - Fundamental to success of SIS films
  - Table rotation used for homogeneity



- Recipe:
  - Temperature: 600°C
  - Pressure: 600mPa
  - Power: 3500 W (8 W/cm<sup>2</sup>)
  - 100% Nitrogen
  - 4 mins =  $\pm$  25 nm





# Future Work

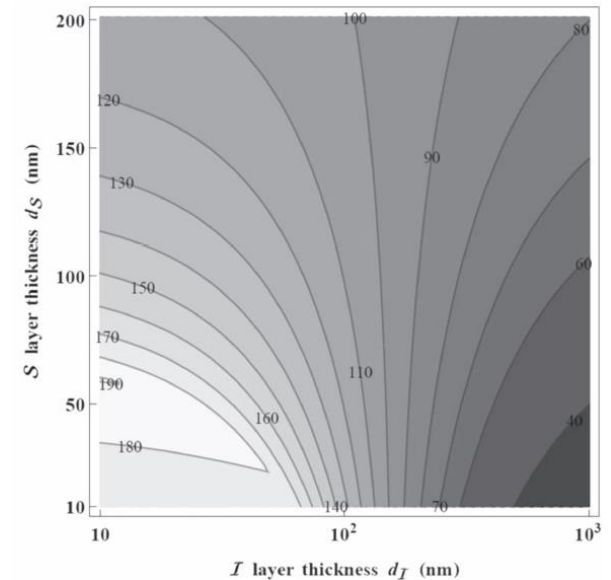
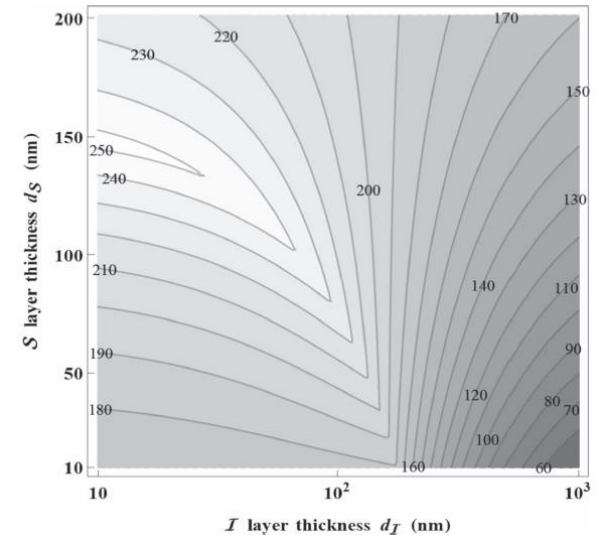
- Initiation of HiPIMS coatings
  - HiPIMS Nb coating
  - HiPIMS NbN coating
- Multilayer Coatings as final goal – NbN/AlN/Nb/Cu
- Nb/Cu QPR sample coatings
  - 2<sup>nd</sup> on EP treated Cu upcoming
  - Multilayer final coating
- PEP investigation

NbN  $\pm$  100 nm

AlN  $\pm$  25 nm

Nb  $\pm$  3  $\mu$ m

Cu Substrate



Predictions of SIS thickness for NbN-I (Kubo, 2017)  
**Top: Clean NbN. Bot: Dirty NbN**

# Thanks for your attention!



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